

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 248684US2SRD		SERIAL NO. <u>10/772,280</u> New Application	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Masahiro KOIKE, et al.			
				FILING DATE Herewith		GROUP <u>2818</u>	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA	S					
	AB						
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	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AO	S					
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
<u>TH</u>	AW	M. R. VISOKAY, et al., "APPLICATION OF HfSiON AS A GATE DIELECTRIC MATERIAL", Applied Physics Letters, Vol. 80, No. 17, April 29, 2002, pgs. 3183-3185					
	AX						
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner <u>TH TH HIO</u>					Date Considered <u>June 2005</u>		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							